NSN 5961-00-472-3540

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View Online at https://aerobasegroup.com/nsn/5961-00-472-3540
Inclosure Material:
Metal
Overall Length:
Between 0.480 inches and 0.535 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-63
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Terminal Circle Diameter:
Between 0.485 inches and 0.515 inches
Features Provided:
Burn in and hermetically sealed case
Overall Width Across Flats:
Between 0.855 inches and 0.875 inches
Thread Size:
0.312 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
60.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 10.0 emitter to
base voltage, static, collector open
Current Rating Per Characteristic:
Between 15.00 amperes source cutoff current and 60.00 amperes source cutoff current
Power Rating Per Characteristic:
200.0 watts small-signal input power, common-collector absolute
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 tab, solder lug and 1 wire hook
Shelf Life:
N/a

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Unit Of Measure:

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No

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